

- High-side switch
- Short-circuit protection
- Input protection
- Overtemperature protection with hysteresis
- Overload protection
- Overvoltage protection
- Switching inductive load
- Clamp of negative output voltage with inductive loads
- Undervoltage shutdown
- Maximum current internally limited
- **Electrostatic discharge (ESD) protection**
- Reverse battery protection<sup>1)</sup>

**SOT-223**


Package: SOT 223

| Type    | Ordering code |
|---------|---------------|
| BSP 452 | Q67000-S271   |

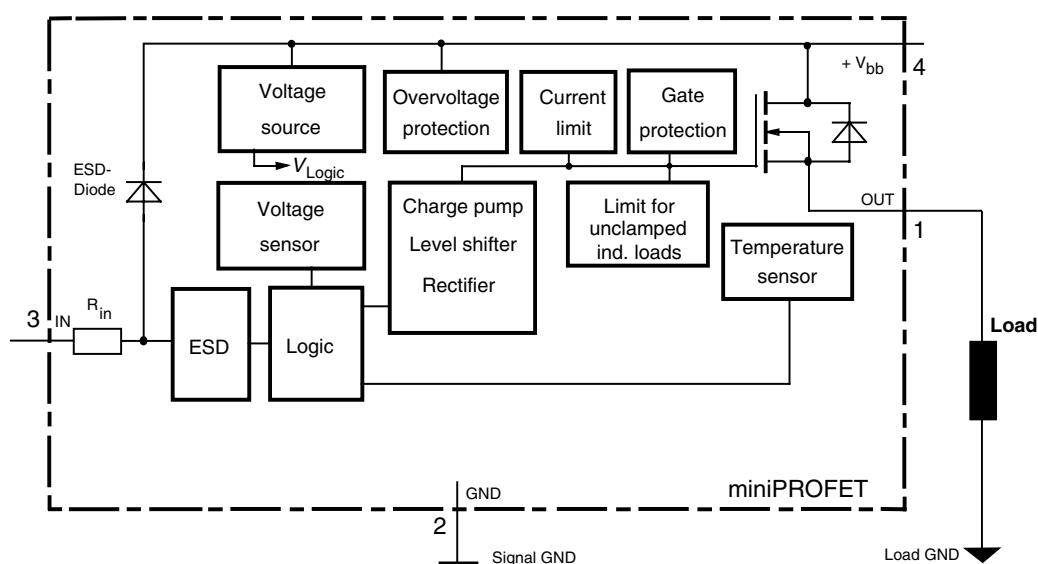
### Application

- µC compatible power switch for 12 V DC grounded loads
- All types of resistive, inductive and capacitive loads
- Replaces electromechanical relays and discrete circuits

### General Description

N channel vertical power FET with charge pump, ground referenced CMOS compatible input, monolithically integrated in Smart SIPMOS® technology. Fully protected by embedded protection functions.

### Blockdiagramm:



<sup>1)</sup> With resistor RGND=150 Ω in GND connection, resistor in series with IN connections reverse load current limited by connected load.

| Pin | Symbol | Function   |
|-----|--------|--|
| 1   | OUT O  | Output to the load   |
| 2   | GND -  | Logic ground   |
| 3   | IN I   | Input, activates the power switch in case of logical high signal |
| 4   | Vbb +  | Positive power supply voltage                                    |

**Maximum Ratings** at  $T_j = 25^\circ\text{C}$  unless otherwise specified

| Parameter  | Symbol                   | Values             | Unit             |
|--|--------------------------|--------------------|------------------|
| Supply voltage   | $V_{bb}$                 | 40                 | V                |
| Load current self-limited  | $I_L$                    | $I_{L(SC)}$        | A                |
| Maximum input voltage <sup>2)</sup>  | $V_{IN}$                 | -5.0... $V_{bb}$   | V                |
| Maximum input current  | $I_{IN}$                 | $\pm 5$            | mA               |
| Inductive load switch-off energy dissipation,<br>single pulse $I_L = 0.5\text{A}$ , $T_A = 150^\circ\text{C}$<br>(not tested, specified by design)   | $E_{AS}$                 | 0.5                | J                |
| Load dump protection <sup>3)</sup> $V_{Load\ Dump} = U_A + V_s$ $R_L = 24\Omega$<br>$R_l = 2\Omega$ , $t_d = 400\text{ms}$ , IN= low or high, $U_A = 13.5\text{V}$ $R_L = 80\Omega$<br>(not tested, specified by design) | $V_{Load\ dump}^4)$      | 60<br>80           | V                |
| Electrostatic discharge capability (ESD) <sup>5)</sup> PIN 3<br>PIN 1,2,4  | $V_{ESD}$                | $\pm 1$<br>$\pm 2$ | kV               |
| Operating temperature range  | $T_j$                    | -40 ...+150        | $^\circ\text{C}$ |
| Storage temperature range  | $T_{stg}$                | -55 ...+150        |                  |
| Max. power dissipation (DC) <sup>6)</sup> $T_A = 25^\circ\text{C}$   | $P_{tot}$                | 1.8                | W                |
| Thermal resistance chip - soldering point:<br>chip - ambient: <sup>6)</sup>  | $R_{thJS}$<br>$R_{thJA}$ | 7<br>70            | K/W              |

<sup>2)</sup> At  $V_{IN} > V_{bb}$ , the input current is not allowed to exceed  $\pm 5$  mA.

<sup>3)</sup> Supply voltages higher than  $V_{bb(AZ)}$  require an external current limit for the GND pin, e.g. with a  $150\ \Omega$  resistor in the GND connection. A resistor for the protection of the input is integrated.

<sup>4)</sup>  $V_{Load\ dump}$  is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839.

<sup>5)</sup> HBM according to MIL-STD 883D, Methode 3015.7

<sup>6)</sup> BSP 452 on epoxy pcb 40 mm x 40 mm x 1.5 mm with  $6\ \text{cm}^2$  copper area for  $V_{bb}$  connection

## Electrical Characteristics

| Parameter and Conditions<br>at $T_j = 25^\circ\text{C}$ , $V_{bb} = 13.5\text{V}$ unless otherwise specified | Symbol | Values |     |     | Unit |
|--|--------|--------|-----|-----|------|
|  |        | min    | typ | max |      |

## Load Switching Capabilities and Characteristics

|  |   |                |     |      |     |                        |
|--|---|----------------|-----|------|-----|------------------------|
| On-state resistance (pin 4 to 1)<br>$I_L = 0.5 \text{ A}$ , $V_{in} = \text{high}$   | $T_j = 25^\circ\text{C}$<br>$T_j = 150^\circ\text{C}$ | $R_{ON}$       | --  | 0.16 | 0.2 | $\Omega$               |
| Nominal load current (pin 4 to 1) <sup>7)</sup><br>ISO Standard: $V_{ON} = V_{bb} - V_{OUT} = 0.5 \text{ V}$<br>$T_S = 85^\circ\text{C}$ |   | $I_{L(ISO)}$   | 0.7 | --   | --  | A                      |
| Turn-on time<br>to 90% $V_{OUT}$   |   | $t_{on}$       | --  | 60   | 100 |                        |
| Turn-off time<br>to 10% $V_{OUT}$  |   | $t_{off}$      | --  | 60   | 150 |                        |
| $R_L = 24 \Omega$  |   |                |     |      |     | $\mu\text{s}$          |
| Slew rate on<br>10 to 30% $V_{OUT}$ , $R_L = 24 \Omega$  |   | $dV/dt_{on}$   | --  | 2    | 4   | $\text{V}/\mu\text{s}$ |
| Slew rate off<br>70 to 40% $V_{OUT}$ , $R_L = 24 \Omega$   |   | $-dV/dt_{off}$ | --  | 2    | 4   | $\text{V}/\mu\text{s}$ |

## Input

|   |                    |      |     |          |                  |
|---|--------------------|------|-----|----------|------------------|
| Allowable input voltage range, (pin 3 to 2)   | $V_{IN}$           | -3.0 | --  | $V_{bb}$ | V                |
| Input turn-on threshold voltage<br>$T_j = -40 \dots +150^\circ\text{C}$   | $V_{IN(T+)}$       | --   | --  | 3.5      | V                |
| Input turn-off threshold voltage<br>$T_j = -40 \dots +150^\circ\text{C}$  | $V_{IN(T-)}$       | 1.5  | --  | --       | V                |
| Input threshold hysteresis  | $\Delta V_{IN(T)}$ | --   | 0.5 | --       | V                |
| Off state input current (pin 3)<br>$V_{IN(off)} = 1.2 \text{ V}$<br>$T_j = -40 \dots +150^\circ\text{C}$          | $I_{IN(off)}$      | 10   | --  | 60       | $\mu\text{A}$    |
| On state input current (pin 3)<br>$V_{IN(on)} = 3.0 \text{ V to } V_{bb}$<br>$T_j = -40 \dots +150^\circ\text{C}$ | $I_{IN(on)}$       | 10   | --  | 100      | $\mu\text{A}$    |
| Input resistance  | $R_{IN}$           | 1.5  | 2.8 | 3.5      | $\text{k}\Omega$ |

<sup>7)</sup>  $I_{L(ISO)}$  is limited by current limitation, see  $I_{L(SC)}$ , next page

| Parameter and Conditions<br>at $T_j = 25^\circ\text{C}$ , $V_{bb} = 13.5\text{V}$ unless otherwise specified | Symbol | Values |     |     | Unit |
|--|--------|--------|-----|-----|------|
|  |        | min    | typ | max |      |

### Operating Parameters

|  |   |                        |     |     |            |               |
|--|---|------------------------|-----|-----|------------|---------------|
| Operating voltage <sup>8)</sup>  | $T_j = -40 \dots +150^\circ\text{C}$                              | $V_{bb(on)}$           | 5.0 | --  | 34         | V             |
| Undervoltage shutdown  | $T_j = -40 \dots +150^\circ\text{C}$                              | $V_{bb(under)}$        | 3.5 | --  | 5          | V             |
| Undervoltage restart   | $T_j = -40 \dots +25^\circ\text{C}$<br>$T_j = +150^\circ\text{C}$ | $V_{bb(u\ rst)}$       | --  | --  | 6.5<br>7.0 | V             |
| Undervoltage restart of charge pump<br>see diagram page 7                          |   | $V_{bb(ucp)}$          | --  | 5.6 | 7          | V             |
| Undervoltage hysteresis<br>$\Delta V_{bb(under)} = V_{bb(u\ rst)} - V_{bb(under)}$ |   | $\Delta V_{bb(under)}$ | --  | 0.3 | --         | V             |
| Overvoltage shutdown   | $T_j = -40 \dots +150^\circ\text{C}$                              | $V_{bb(over)}$         | 34  | --  | 42         | V             |
| Overvoltage restart  | $T_j = -40 \dots +150^\circ\text{C}$                              | $V_{bb(o\ rst)}$       | 33  | --  | --         | V             |
| Overvoltage hysteresis   | $T_j = -40 \dots +150^\circ\text{C}$                              | $\Delta V_{bb(over)}$  | --  | 0.7 | --         | V             |
| Standby current (pin 4), $V_{in} = \text{low}$                                     | $T_j = -40 \dots +150^\circ\text{C}$                              | $I_{bb(off)}$          | --  | 10  | 25         | $\mu\text{A}$ |
| Operating current (pin 2), $V_{in} = 5\text{ V}$                                   |   | $I_{GND}$              | --  | 1   | 1.6        | mA            |
| leakage current (pin 1) $V_{in} = \text{low}$                                      | $T_j = -40 \dots +25^\circ\text{C}$<br>$T_j = 150^\circ\text{C}$  | $I_{L(off)}$           | --  | 2   | 5<br>7     | $\mu\text{A}$ |

### Protection Functions

|  |                                      |              |     |     |     |                  |
|--|--------------------------------------|--------------|-----|-----|-----|------------------|
| Current limit (pin 4 to 1)   | $T_j = 25^\circ\text{C}$             | $I_{L(SC)}$  | 0.7 | 1.5 | 2   | A                |
| $V_{bb} = 20\text{V}$  | $T_j = -40 \dots +150^\circ\text{C}$ |              | 0.7 | --  | 2.4 |                  |
| Overvoltage protection $I_{bb}=4\text{mA}$   | $T_j = -40 \dots +150^\circ\text{C}$ | $V_{bb(AZ)}$ | 41  | --  | --  | V                |
| Output clamp (ind. load switch off)<br>at $V_{OUT}=V_{bb}-V_{ON(CL)}$ , $I_{bb} = 4\text{mA}$  |                                      | $V_{ON(CL)}$ | 41  | 47  | --  | V                |
| Thermal overload trip temperature  | $T_{jt}$                             |              | 150 | --  | --  | $^\circ\text{C}$ |
| Thermal hysteresis   | $\Delta T_{jt}$                      |              | --  | 10  | --  | K                |
| Inductive load switch-off energy dissipation <sup>9)</sup><br>$T_j \text{ Start} = 150^\circ\text{C}$ , single pulse, $I_L = 0.5\text{ A}$ , $V_{bb} = 12\text{ V}$<br>(not tested, specified by design) |                                      | $E_{AS}$     | --  | --  | 0.5 | J                |
| Reverse battery (pin 4 to 2) <sup>10)</sup><br>(not tested, specified by design)   | $-V_{bb}$                            |              | --  | --  | 30  | V                |

<sup>8)</sup> At supply voltage increase up to  $V_{bb}= 5.6\text{ V typ}$  without charge pump,  $V_{OUT} \approx V_{bb} - 2\text{ V}$

<sup>9)</sup> While demagnetizing load inductance, dissipated energy in PROFET is  $E_{AS} = \int V_{ON(CL)} * i_L(t) dt$ , approx.

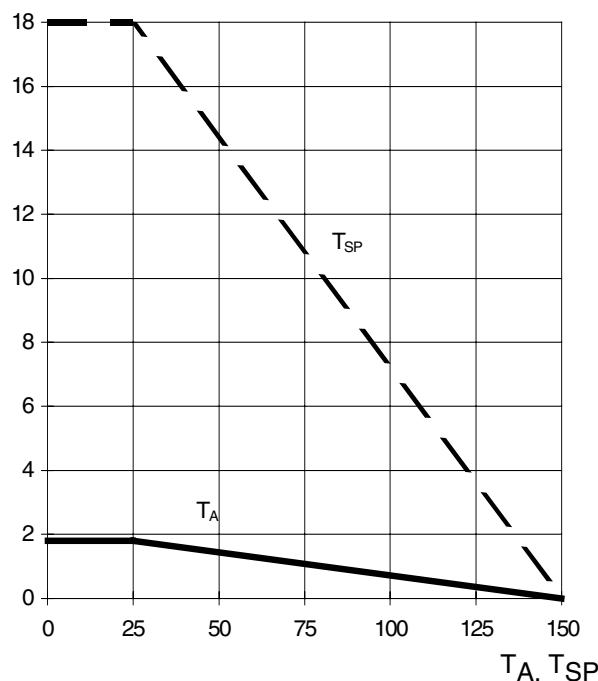
$$E_{AS} = \frac{1}{2} * L * I_L^2 * \frac{V_{ON(CL)}}{(V_{ON(CL)} - V_{bb})}$$

<sup>10)</sup> Requires 150  $\Omega$  resistor in GND connection. Reverse load current (through intrinsic drain-source diode) is normally limited by the connected load.

**Max. allowable power dissipation**

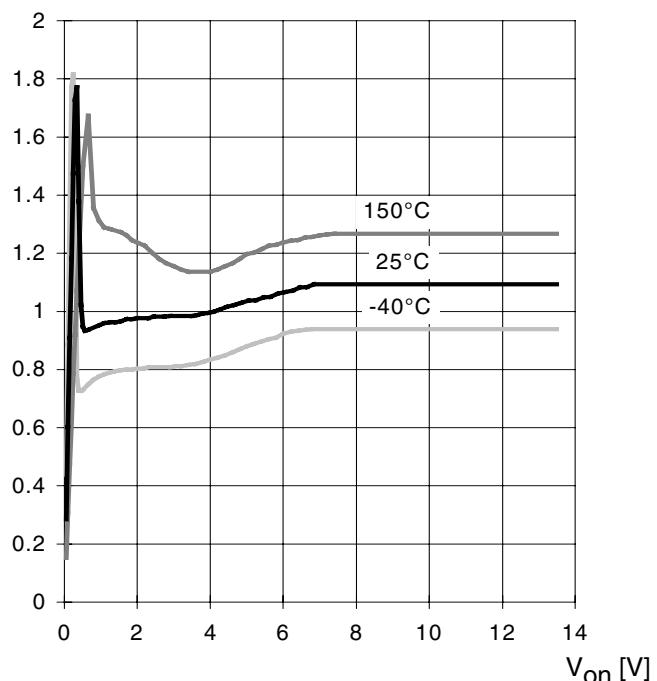
$$P_{\text{tot}} = f(T_A, T_{\text{SP}})$$

$P_{\text{tot}}$  [W]


**Current limit characteristic**

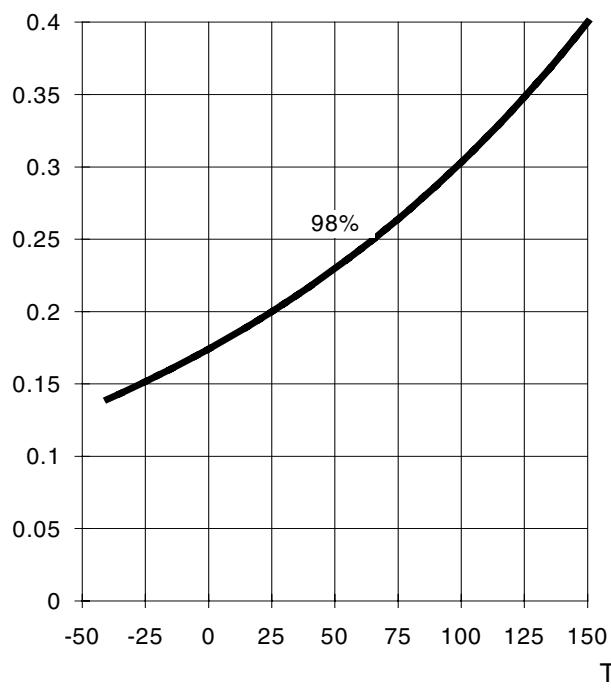
$$I_L(\text{SC}) = f(V_{\text{on}}); (V_{\text{on}} \text{ see testcircuit})$$

$I_L(\text{SC})$  [A]


**On state resistance (Vbb-pin to OUT-pin)**

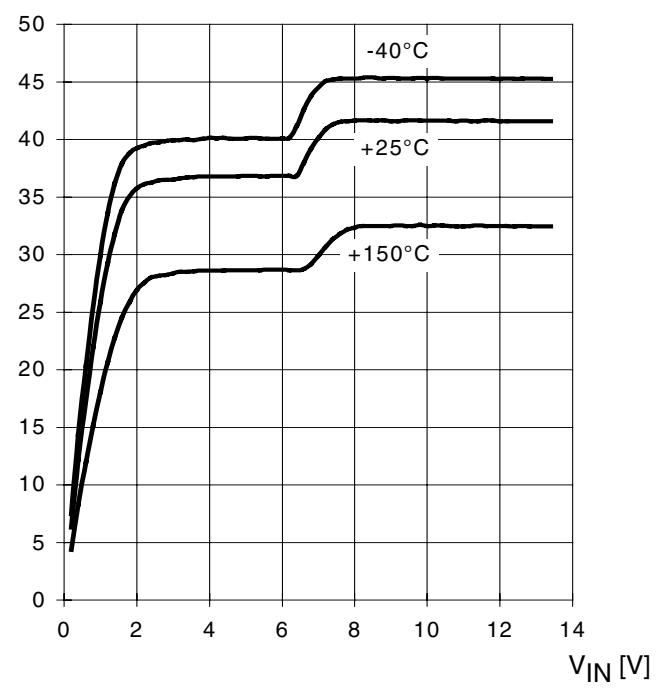
$$R_{\text{ON}} = f(T_j); V_{\text{bb}} = 13.5 \text{ V}; I_L = 0.5 \text{ A}$$

$R_{\text{ON}}$  [ $\Omega$ ]

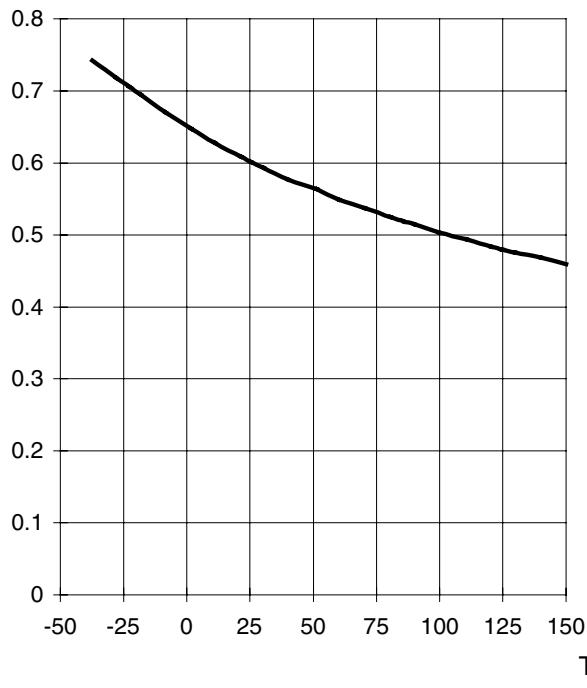
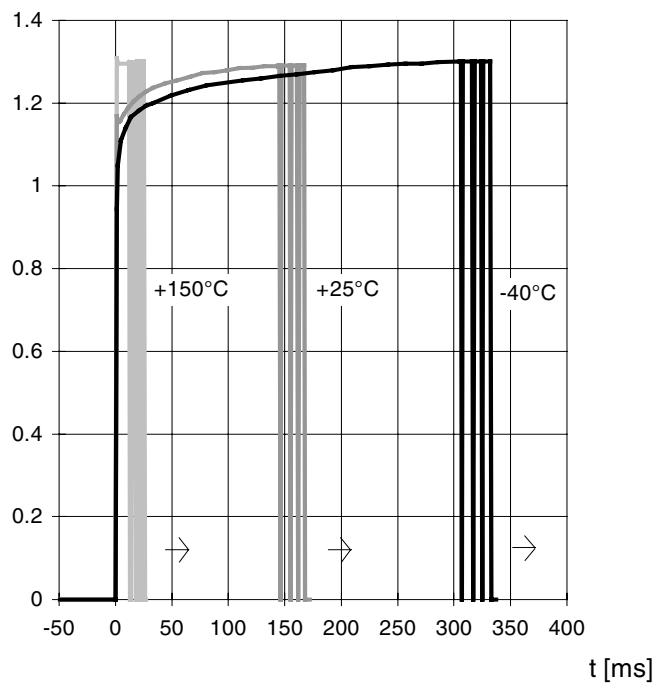

**Typ. input current**

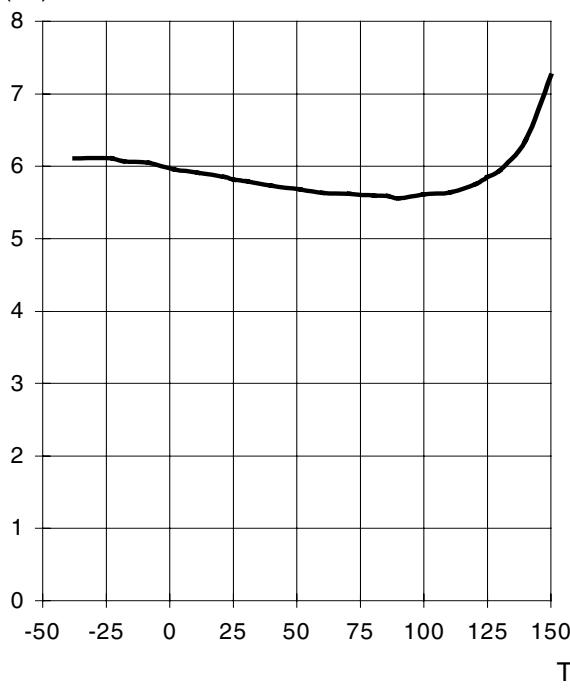
$$I_{\text{IN}} = f(V_{\text{IN}}); V_{\text{bb}} = 13.5 \text{ V}$$

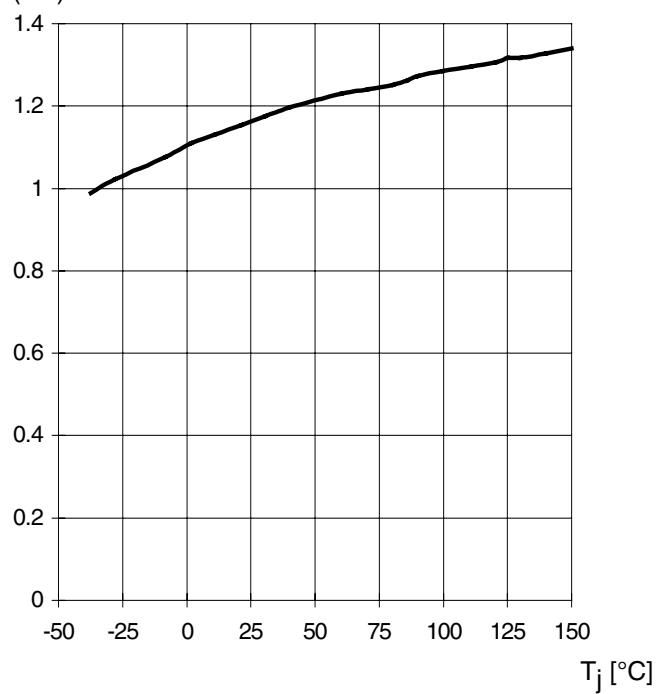
$I_{\text{IN}}$  [ $\mu\text{A}$ ]



**Typ. operating current**
 $I_{GND} = f(T_j)$ ;  $V_{bb} = 13.5$  V;  $V_{IN}$  = high

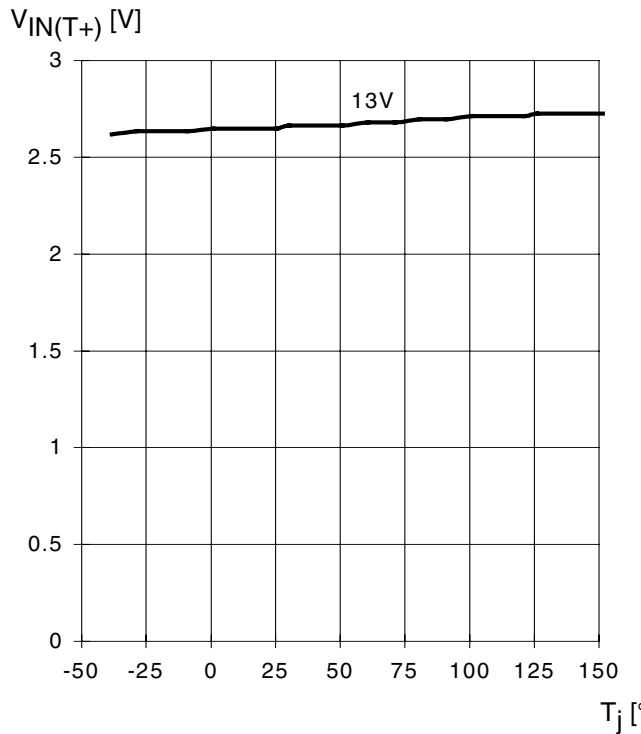
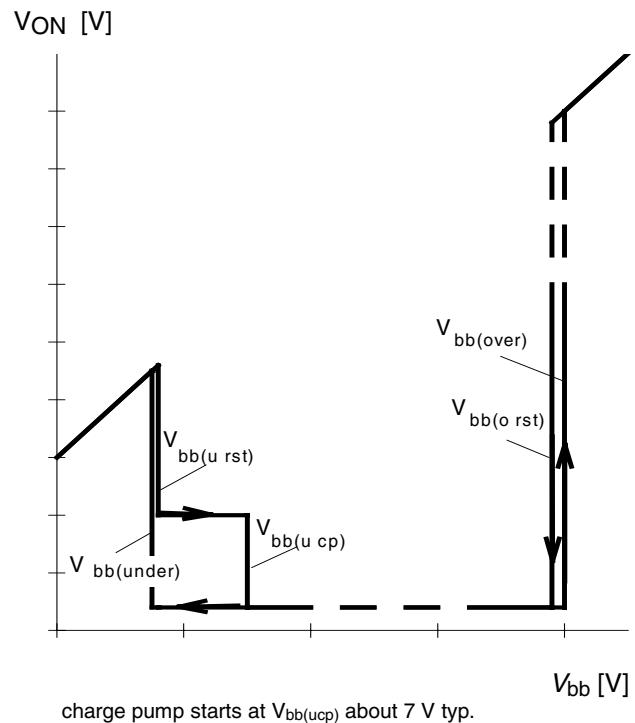
 $I_{GND}$  [mA]

**Typ. overload current**
 $I_L(\text{lim}) = f(t)$ ;  $V_{bb} = 13.5$  V, no heatsink, Param.:  $T_{j,\text{start}}$ 
 $I_L(\text{lim})$  [A]

**Typ. standby current**
 $I_{bb(\text{off})} = f(T_j)$ ;  $V_{bb} = 13.5$  V;  $V_{IN}$  = low

 $I_{bb(\text{off})}$  [ $\mu\text{A}$ ]

**Short circuit current**
 $I_{L(\text{SC})} = f(T_j)$ ;  $V_{bb} = 13.5$  V

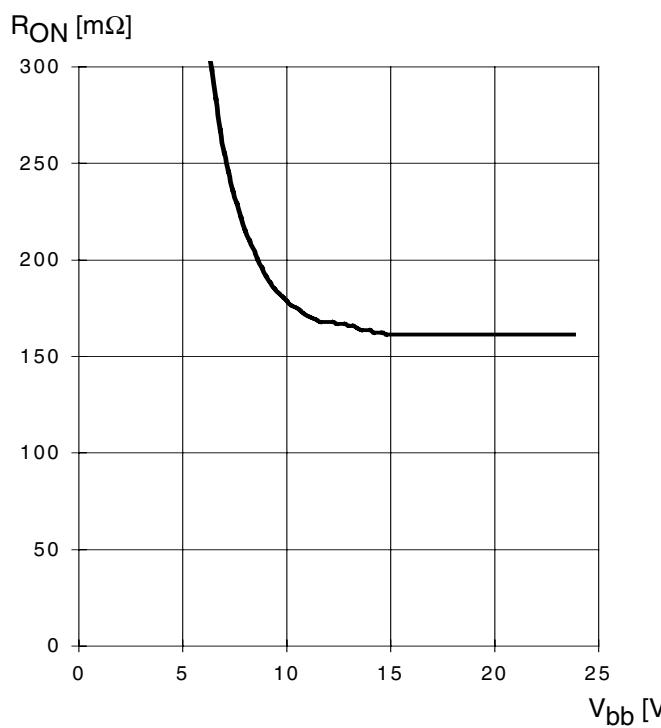
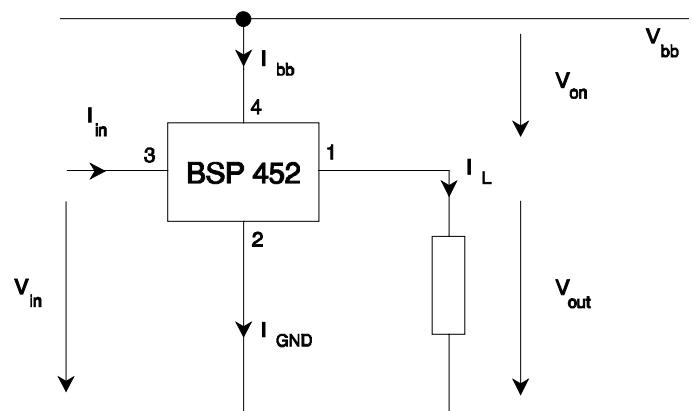
 $I_{L(\text{SC})}$  [A]


**Typ. input turn on voltage threshold**

$$V_{IN(T+)} = f(T_j);$$


**Figure 6: Undervoltage restart of charge pump**

**Typ. on-state resistance (Vbb-Pin to Out-Pin)**

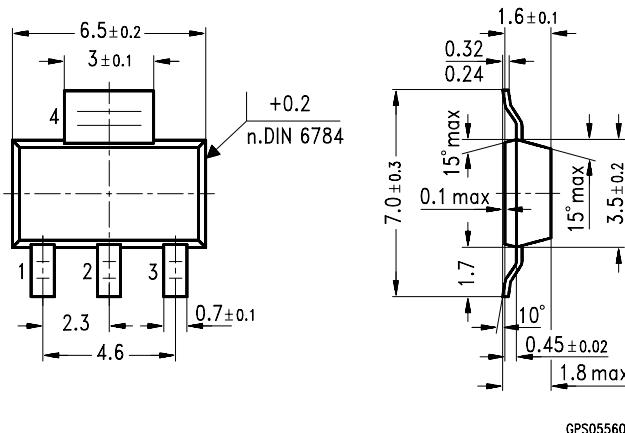
$$R_{ON} = f(V_{bb}, I_L); I_L = 0.5A, T_j = 25^\circ C$$


**Test circuit**


## Package:

all dimensions in mm.

SOT 223/4:



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